imall

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



Contact us

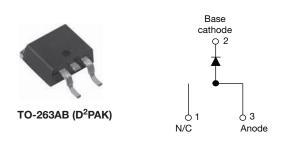
Tel: +86-755-8981 8866 Fax: +86-755-8427 6832 Email & Skype: info@chipsmall.com Web: www.chipsmall.com Address: A1208, Overseas Decoration Building, #122 Zhenhua RD., Futian, Shenzhen, China



Vishay Semiconductors

www.vishay.com

High Performance Schottky Rectifier, 20 A



PRODUCT SUMMARY								
I _{F(AV)}	20 A							
V _R	15 V							
V _F at I _F	0.33 V							
I _{RM} max.	600 mA at 100 °C							
T _J max.	125 °C							
E _{AS}	10 mJ							
Package	TO-263AB (D ² PAK)							
Diode variation	Single die							

FEATURES

- 125 °C T_J operation ($V_R < 5 V$)
- Center tap module
- Optimized for OR-ing applications
- Ultralow forward voltage drop
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- AEC-Q101 qualified
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

DESCRIPTION

The Schottky rectifier module has been optimized for ultralow forward voltage drop specifically for the OR-ing of parallel power supplies. The proprietary barrier technology allows for reliable operation up to 125 °C junction temperature. Typical applications are in parallel switching power supplies, converters, reverse battery protection, and redundant power subsystems.

MAJOR RATINGS AND CHARACTERISTICS									
SYMBOL	CHARACTERISTICS	VALUES	UNITS						
I _{F(AV)}	Rectangular waveform	20	А						
V _{RRM}		15	V						
I _{FSM}	t _p = 5 μs sine	700	А						
V _F	19 A_{pk} , T_J = 125 °C (typical)	0.25	V						
TJ	Range	-55 to +125	°C						

VOLTAGE RATINGS								
PARAMETER	SYMBOL	TEST CONDITIONS	VS-STPS20L15GPbF	UNITS				
Maximum DC reverse voltage	V _R	T ₁ = 100 °C	15	V				
Maximum working peak reverse voltage	V _{RWM}	1J = 100 C	15	V				

ABSOLUTE MAXIMUM RATINGS									
PARAMETER	SYMBOL	TEST COND	VALUES	UNITS					
Maximum average forward current See fig. 5	I _{F(AV)}	50 % duty cycle at $T_C = 85$ °C,	20						
Maximum peak one cycle		5 µs sine or 3 µs rect. pulse	Following any rated load	700	A				
non-repetitive surge current See fig. 7	IFSM	10 ms sine or 6 ms rect. pulse	condition and with rated V _{RRM} applied	330					
Non-repetitive avalanche energy	E _{AS}	$T_J = 25 \text{ °C}, I_{AS} = 2 \text{ A}, L = 6 \text{ mH}$	10	mJ					
Repetitive avalanche current	I _{AR}	Current decaying linearly to zero Frequency limited by T _J maximu	2	А					

Revision: 29-Jul-14

For technical questions within your region: <u>DiodesAmericas@vishay.com</u>, <u>DiodesAsia@vishay.com</u>, <u>DiodesEurope@vishay.com</u> THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT <u>www.vishay.com/doc?91000</u>

1





www.vishay.com

Vishay Semiconductors

ELECTRICAL SPECIFICATIONS									
PARAMETER	SYMBOL	TEST CO	TYP.	MAX.	UNITS				
		19 A	T.I = 25 °C	-	0.41				
Forward voltage drop See fig. 1	V _{FM} ⁽¹⁾	40 A	1j=25 0	-	0.52	V			
	V FM (*)	19 A	− T _{.1} = 125 °C	0.25	0.33				
		40 A	1j = 125 0	0.37	0.50				
Reverse leakage current	I _{RM} ⁽¹⁾	T _J = 25 °C	$V_{\rm B}$ = Rated $V_{\rm B}$	-	10	mA			
See fig. 2	IRM \''	T _J = 100 °C	VR = naleu VR	-	600	ШA			
Threshold voltage	V _{F (TO)} 0.182		T. T. M. M. M.						
Forward slope resistance	r _t	$T_J = T_J$ maximum	7.6		mW				
Maximum junction capacitance	CT	$V_R = 5 V_{DC}$ (test signal range	-	2000	pF				
Typical series inductance	L _S	Measured lead to lead 5 n	8	-	nH				
Maximum voltage rate of change	dV/dt	Rated V _R	Rated V _R 10 000 V/µ						

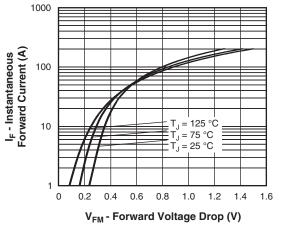
Note

 $^{(1)}\,$ Pulse width < 300 $\mu s,$ duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS								
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS			
Maximum junction temperatu	ire range	TJ		-55 to +125	°C			
Maximum storage temperatu	re range	T _{Stg}		-55 to +150	C			
Maximum thermal resistance, junction to case		R _{thJC}	DC operation See fig. 4	1.5				
Typical thermal resistance, case to heatsink		R _{thCS}	Mounting surface, smooth and greased (for TO-220)	0.50	°C/W			
Maximum thermal resistance, junction to ambient		R _{thJA}	DC operation (for D ² PAK)	40				
Approvimate weight				2	g			
Approximate weight				0.07	oz.			
Mounting torque	minimum		Non-lubricated threads	6 (5)	kqf · cm			
Mounting torque —	maximum				(lbf ⋅ in)			
Marking device			Case style D ² PAK	STPS2	DL15G			

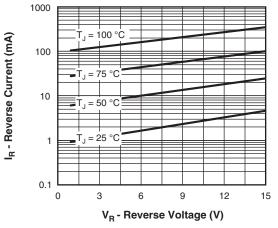
VS-STPS20L15GPbF

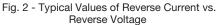
Vishay Semiconductors



www.vishay.com

Fig. 1 - Maximum Forward Voltage Drop Characteristics





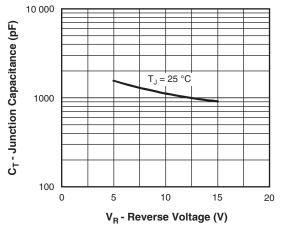


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

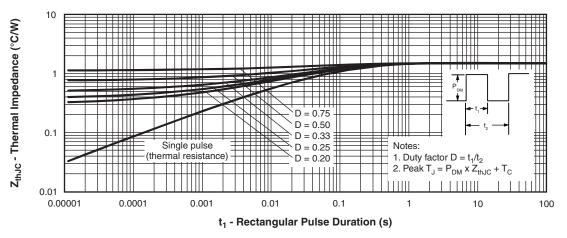
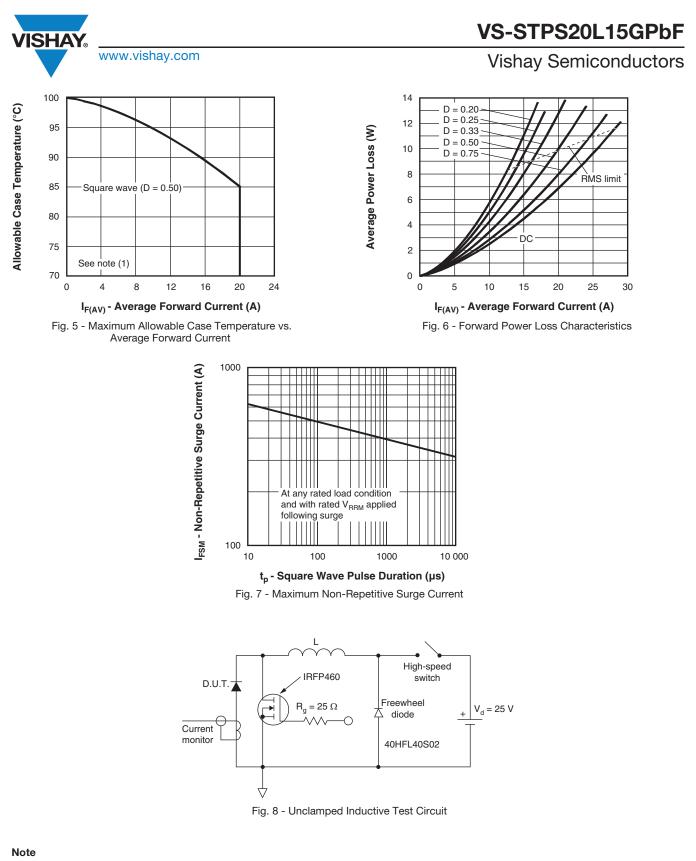


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics

Revision: 29-Jul-14

3

For technical questions within your region: <u>DiodesAmericas@vishay.com</u>, <u>DiodesAsia@vishay.com</u>, <u>DiodesEurope@vishay.com</u> THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT <u>www.vishay.com/doc?91000</u>



Revision: 29-Jul-14

4

For technical questions within your region: <u>DiodesAmericas@vishay.com</u>, <u>DiodesAsia@vishay.com</u>, <u>DiodesEurope@vishay.com</u> THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT <u>www.vishay.com/doc?91000</u>



Vishay Semiconductors



ORDERING INFORMATION TABLE

Device code	VS-	STPS	20	L	15	G	TRL	PbF
		2	3	4	5	6	7	8
	1 2 3 4 5	- Esso - Curi - Low - Volt	ential pa rent rati v voltage age rati	ng (15 =	20 A) 15 V)	oduct		
	 G = D²PAK package 7 - • None = tube 							
				e and re	`		,	
	8	- • Pk	oF = lea	be and ro d (Pb)-fr Pb)-free	ee (for l	D ² PAK	tube)	

ORDERING INFORMATION (Example)								
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION					
VS-STPS20L15GPbF	50	1000	Antistatic plastic tubes					
VS-STPS20L15GTRLP	800	800	13" diameter reel					
VS-STPS20L15GTRRP	800	800	13" diameter reel					

LINKS TO RELATED DOCUMENTS						
Dimensions	www.vishay.com/doc?95046					
Part marking information	www.vishay.com/doc?95054					
Packaging information	www.vishay.com/doc?95032					

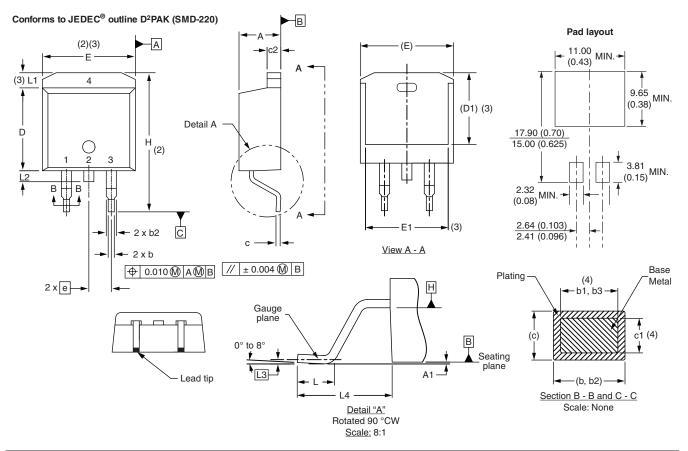
Outline Dimensions



Vishay Semiconductors

D²PAK

DIMENSIONS in millimeters and inches



SYMBOL	MILLIM	ETERS	INC	HES	NOTES		SYMBOL	MILLIM	ETERS	INC	HES	NOTES
STMBOL	MIN.	MAX.	MIN.	MAX.	NOTES		STINDUL	MIN.	MAX.	MIN.	MAX.	NOTES
A	4.06	4.83	0.160	0.190			D1	6.86	8.00	0.270	0.315	3
A1	0.00	0.254	0.000	0.010			E	9.65	10.67	0.380	0.420	2, 3
b	0.51	0.99	0.020	0.039			E1	7.90	8.80	0.311	0.346	3
b1	0.51	0.89	0.020	0.035	4		е	2.54	BSC	0.100	BSC	
b2	1.14	1.78	0.045	0.070			Н	14.61	15.88	0.575	0.625	
b3	1.14	1.73	0.045	0.068	4		L	1.78	2.79	0.070	0.110	
С	0.38	0.74	0.015	0.029			L1	-	1.65	-	0.066	3
c1	0.38	0.58	0.015	0.023	4		L2	1.27	1.78	0.050	0.070	
c2	1.14	1.65	0.045	0.065			L3	0.25	BSC	0.010	BSC	
D	8.51	9.65	0.335	0.380	2		L4	4.78	5.28	0.188	0.208	

Notes

⁽¹⁾ Dimensioning and tolerancing per ASME Y14.5 M-1994

(2) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body

⁽³⁾ Thermal pad contour optional within dimension E, L1, D1 and E1

⁽⁴⁾ Dimension b1 and c1 apply to base metal only

⁽⁵⁾ Datum A and B to be determined at datum plane H

⁽⁶⁾ Controlling dimension: inch

⁽⁷⁾ Outline conforms to JEDEC[®] outline TO-263AB

Revision: 08-Jul-15

1

Document Number: 95046

For technical questions within your region: <u>DiodesAmericas@vishay.com</u>, <u>DiodesAsia@vishay.com</u>, <u>DiodesEurope@vishay.com</u> THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT <u>www.vishay.com/doc?91000</u>



Vishay

Disclaimer

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and / or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Except as expressly indicated in writing, Vishay products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the Vishay product could result in personal injury or death. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.